

**Maximum Ratings**

Symbol	Conditions	Values	Units
$V_{CEVsus}$	$I_C = 1 A, V_{BE} = -2 V$	1200	V
$V_{CEV}$	$V_{BE} = -2 V$	1200	V
$V_{CBO}$	$I_E = 0$	1200	V
$V_{EBO}$	$I_C = 0$	7	V
$I_C$	D. C.	100	A
$I_{CM}$	$t_p = 1 ms$	200	A
$I_F = -I_C$		100	A
$I_B$		5	A
$P_{tot}$	$T_{case} = 25 °C$ ; per darlington	800	W
$T_{vj}$		-40 ... +150	°C
$T_{stg}$		-40 ... +125	°C
$V_{isol}$	a. c. 50 Hz, r.m.s.	2500~	V

**Thermal Characteristics**

$R_{thjc}$	per darlington/per module	0,155/0,077	°C/W
$R_{thjc}$	per diode/per module	0,65/0,325	°C/W
$R_{thch}$	per 1/2 module/per module	0,075/0,038	°C/W

**Electrical Characteristics<sup>1)</sup>**

		min.	typ.	max.	
$I_{CEV}$	$V_{CE} = V_{CEV}, V_{BE} = -2 V$			2	mA
$I_{EBO}$	$I_C = 0, V_{BE} = -7 V$			400	mA
$V_{CEsat}^{2)}$	$I_C = 100 A, I_B = 2 A$			3	V
$V_{BEsat}^{2)}$	$I_C = 100 A, I_B = 2 A$			3,5	V
$h_{21E}^{2)}$	$I_C = 100 A$ $V_{CE} = 5 V$	75			

**Switching Characteristics for Resistive Load<sup>1)</sup>**

$t_{on}$	$I_C = 100 A$ $I_{B1} = -I_{B2} = 2 A$ $V_{CC} = 600 V$			3	µs
$t_s$				15	µs
$t_r$				3	µs

**Inverse Diode Characteristics<sup>1)</sup>**

$V_F = -V_{CE}$	$I_F = -I_C = 100 A$			1,8	V
$I_{FSM} = -I_{Cp}$	sin 180°, 10 ms	1000			A
$I_{RM}$	$I_F = -I_C = 100 A, -di_F/dt = 100 A/µs$ $V_{BE} = -3 V, V_R = V_{CE} = 400 V,$ $T_{vj} = 125 °C$			38	A
$Q_{rr}$				19	µC

**Mechanical Data**

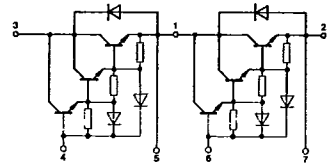
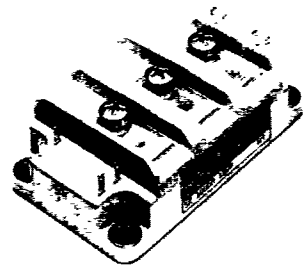
$M_1$	Case to heatsink	SI units	3		6	Nm
		US units	27		53	lb. in.
$M_2$	Busbars to terminals	SI units	2,5		5	Nm
		US units	22		44	lb. in.
w			420			g
Case			D 14			

**SEMITRANS® 3 NPN**

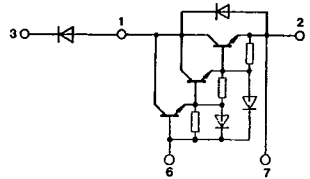
**Power Darlington Modules**  
100 A, 1200 V

SK 100 DB 120 D  
SK 100 DAL 120 D

T-33-35



**DB**



**DAL**

**Features**

- Isolated baseplate (ease of mounting of one or several modules on one heatsink)
- All electrical connections on top (ease of interconnecting of modules with busbars/PCB)
- Large clearances and creepage distances
- Parallel connected fast recovery inverse diode
- UL recognized, file no. 63 532

**Typical Applications**

- Switched mode power supplies
- DC servo and robot drives
- AC motor controls
- Brake choppers (DAL)

<sup>1)</sup>  $T_{case} = 25 °C$  unless otherwise stated

<sup>2)</sup>  $t_p \leq 300 µs, D \leq 1,5 %$

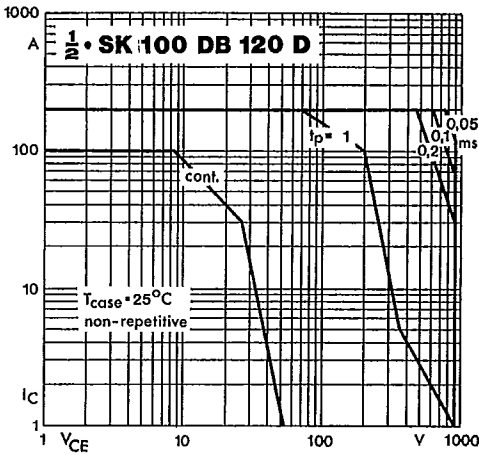


Fig. 1 Forward biased safe operating area (FBSOA)

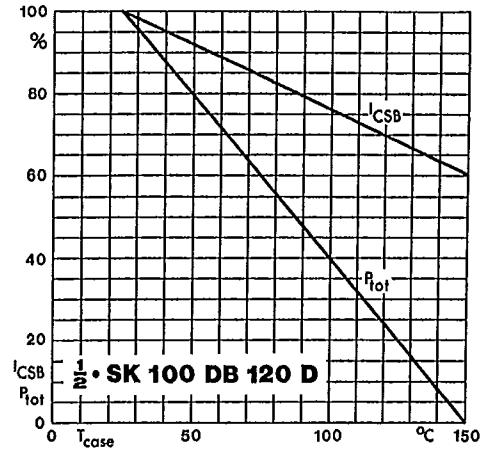


Fig. 2 Shifting the limits of the FBSOA with temperature

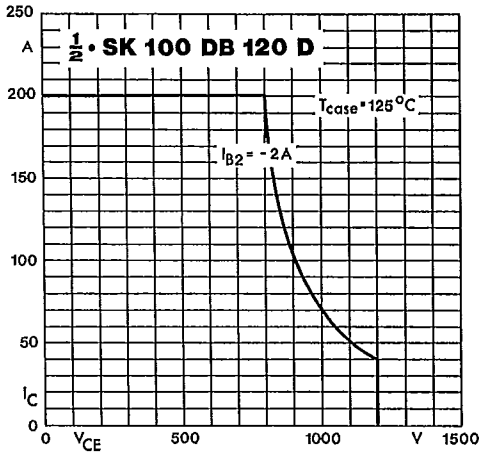


Fig. 3 Reverse biased safe operating area (RBSOA)

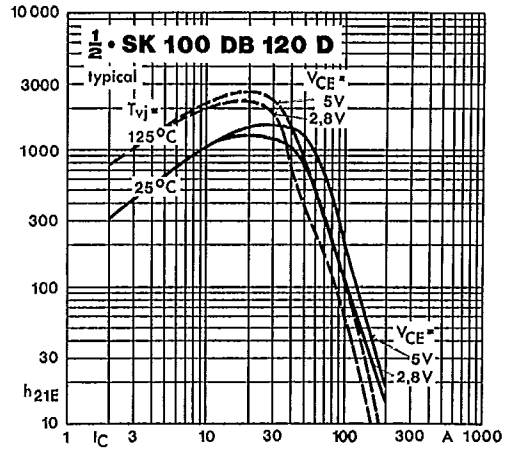


Fig. 4 Forward current transfer ratio vs. coll. current

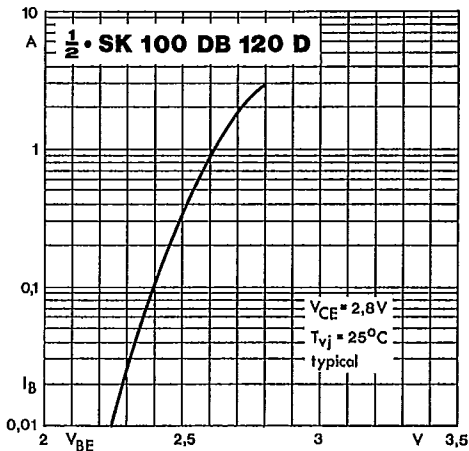


Fig. 5 Base current/voltage characteristic

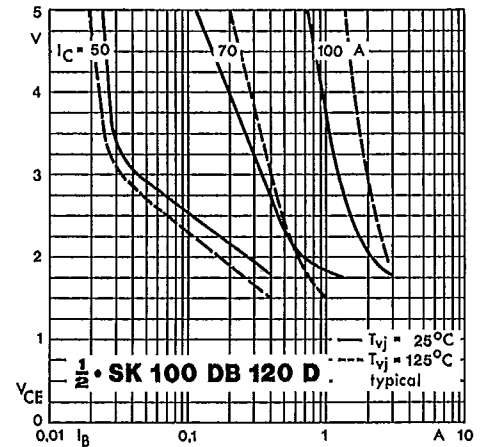


Fig. 6 Collector-emitter voltage vs. base current

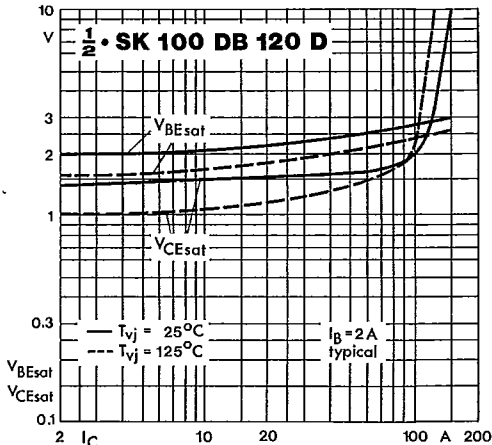


Fig. 7 Saturation voltages vs. collector current

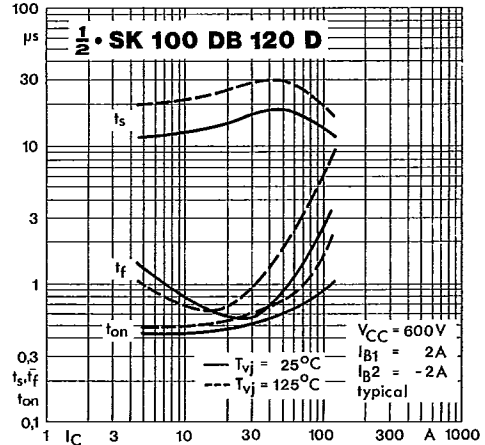


Fig. 8 Switching times vs. collector current

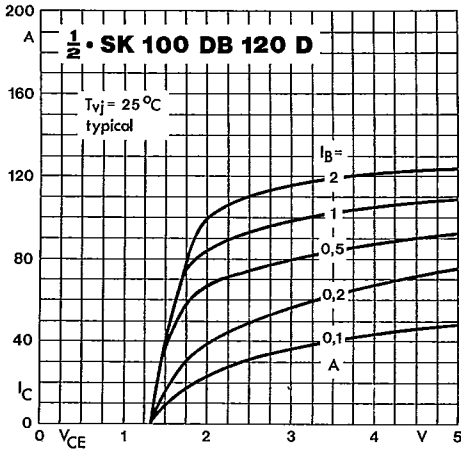


Fig. 9 Collector current/voltage characteristics

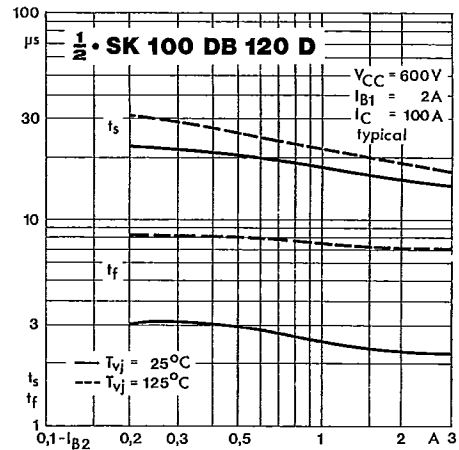


Fig. 10 Turn-off times vs. negative base current

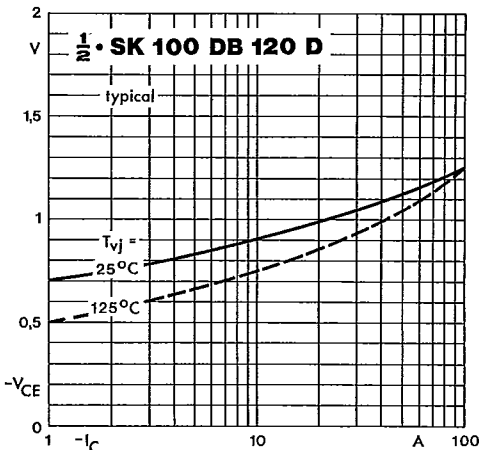


Fig. 11 Inverse diode forward characteristics

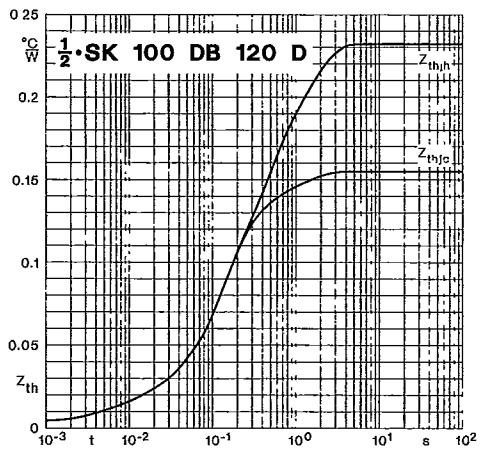


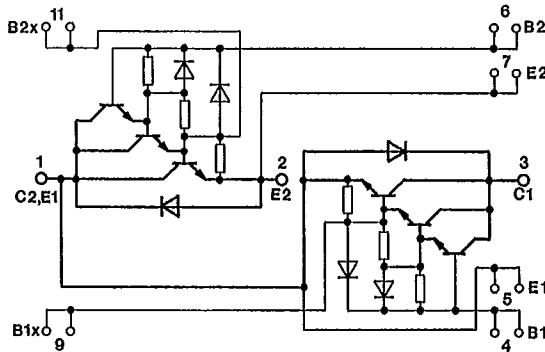
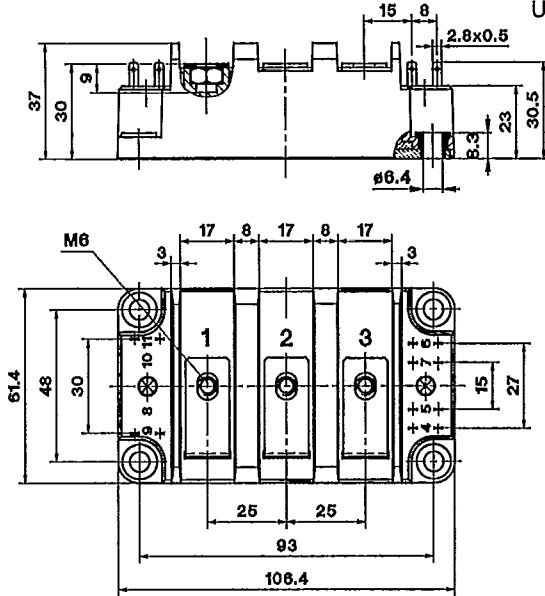
Fig. 12 Transient thermal impedance vs. time

**SK 100 DB 120 D**

SEMITRANS® 3

Case D 14

UL recognized, file no. 63 532



Dimensions in mm

**SK 100 DAL 120 D**

SEMITRANS® 3

Case D 39

UL recognized, file no. E 63 532

